



BYD Microelectronics Co., Ltd.

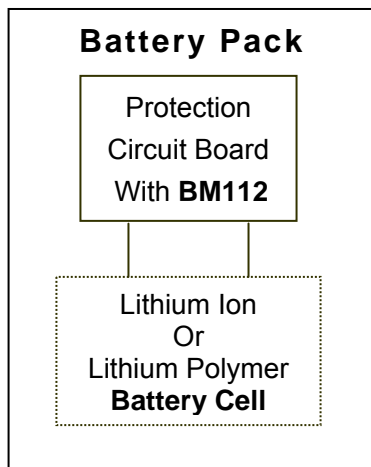
# BM112 Series

## One-Cell Li Battery Protectors

### General Description

The BM112 Series are protectors for lithium-ion and lithium polymer rechargeable battery with high accuracy voltage detection. They can be used for protecting single cell lithium-ion or/and lithium polymer battery packs from overcharge, over-discharge, excess current and short circuit. These ICs have suitable protection delay functions and low power consumption property.

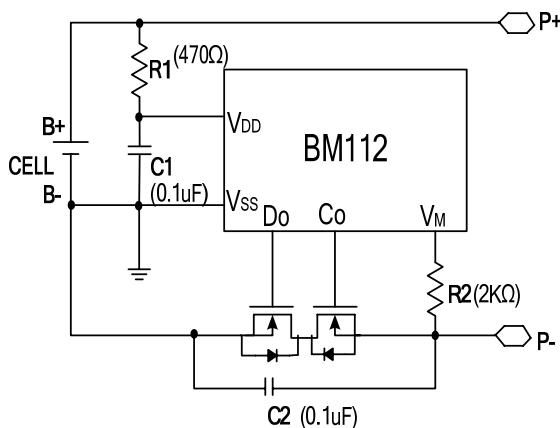
### Applications



### Features

- **Overcharge Threshold**
  - 4.200~4.400V
  - Accuracy  $\pm 25\text{mV}$  (25°C)  
 $\pm 50\text{mV}$  (-30°C~80°C)
- **Over-discharge Threshold**
  - 2.30V~3.00V
  - Accuracy  $\pm 75\text{mV}$
- **Excess Current Protection Threshold**
  - 0.05V~0.150V @  $V_{DD} = 3.30\text{V}$
  - Accuracy  $\pm 0.015\text{V}$
- **Short Circuit Protection Threshold**
  - Typ. 0.80V @  $V_{DD} = 3.30\text{V}$
  - Accuracy  $\pm 0.15\text{V}$
- **Low Supply Current**
  - Typ. 4.0uA @  $V_{DD} = 3.9\text{V}$  (Standard working)
  - Typ. 0.1uA @  $V_{DD} = 2.0\text{V}$  (Without auto wake up)
  - Typ. 1.8uA @  $V_{DD} = 2.0\text{V}$  (With auto wake up)
- **Small Package**
  - SOT-23-6L
  - DFNWB2\*2-6L

### Typical Application Circuits



### Notes

$R_1$  and  $C_1$  are to stabilize the supply voltage of the BM112 series.  $R_1$   $C_1$  is hence regarded as the time constant for  $V_{DD}$  pin.  $C_2$  is to stabilize the voltage of  $V_M$  pin.  $R_1$  and  $R_2$  can also be a part of current limit circuit for the BM112 series. Recommended values of these elements are as follows:

- $R_1 < 1\text{k}\Omega$ . A larger value of  $R_1$  results in higher detection voltage, introducing errors.
- $R_2 < 2.5\text{k}\Omega$ . A larger value of  $R_2$  possibly prevents resetting from over-discharge even with a charger.
- $R_1 + R_2 > 1\text{k}\Omega$ . Smaller values may lead to power consumption over the maximum dissipation rating of the BM112 series.
- The above diagram and parameters can't insure the circuit work well, please choose the suitable parameters through test.



## Selection Guide

- **Type Number**

**BM112 – XXXX – YY**

| Symbol | Meaning  | Description                         |
|--------|--|-------------------------------------|
| XXXX   | First X: Overcharge detection threshold voltage (Vdet1),<br>Second X: Over discharge detection threshold voltage (Vdet2),<br>Third X: Excess current 1 detection threshold voltage (Vdet3),<br>Fourth X: other parameters or versions. | Assigned from AAAA to<br>WWWW       |
| YY     | Package  | ST : SOT-23-6L<br>CE : DFNWB2*2-6L. |

- **Type Number Option**

Through choosing the “XXXX”, Vdet1, Vdet2, Vdet3 and Versions can be decided. Through choosing the “YY”, the package can be decided. Table 1 to Table 3 also show part of the corresponding information.

**Product List****Table 1.****( @ 25℃ )**

| Type Number | Over charge threshold (Vdet1) | Over charge release hysteresis voltage (Vhc) | Over discharge threshold (Vdet2) | Over discharge release hysteresis voltage (Vhd) | Discharge over current threshold (Vdet3) | Abnormal Charge Current threshold (Vcha) | Auto wake up function | Delay time combination | Mark (ST/CE)   |
|-------------|-------------------------------|--|----------------------------------|---|--|--|-----------------------|------------------------|----------------|
| BM112-KFCA  | 4.225V                        | 0.1V   | 2.85V                            | 0.30V   | 0.100V                                   | -0.120V                                  | No                    | (2)                    | PBKXX/<br>CEXX |
| BM112-KFEA  | 4.225V                        | 0.2V   | 2.85V                            | 0V  | 0.150V                                   | -0.120V                                  | No                    | (3)                    | PGKXX/<br>CFXX |
| BM112-LACB  | 4.275V                        | 0.1V   | 2.29V                            | 0.10V   | 0.100V                                   | -0.100V                                  | Yes                   | (2)                    | PHLXX/<br>COXX |
| BM112-LA    | 4.275V                        | 0.1V   | 2.29V                            | 0.10V   | 0.150V                                   | -0.120V                                  | No                    | (1)                    | PCLXX/<br>CLXX |
| BM112-LAEB  | 4.275V                        | 0.1V   | 2.29V                            | 0.10V   | 0.150V                                   | -0.120V                                  | Yes                   | (1)                    | PPLXX/<br>CGXX |
| BM112-LFAA  | 4.275V                        | 0.1V   | 2.88V                            | 0.13V   | 0.050V                                   | -0.075V                                  | No                    | (2)                    | PDLXX/<br>CHXX |
| BM112-LFCA  | 4.275V                        | 0.1V   | 2.88V                            | 0.30V   | 0.100V                                   | -0.120V                                  | No                    | (2)                    | PBLXX/<br>CCXX |
| BM112-LFEA  | 4.275V                        | 0.2V   | 2.88V                            | 0V  | 0.150V                                   | -0.120V                                  | No                    | (3)                    | PGLXX/<br>CDXX |
| BM112-HAEA  | 4.325V                        | 0.1V   | 2.31V                            | 0.10V   | 0.150V                                   | -0.120V                                  | No                    | (1)                    | PCHXX/<br>CBXX |
| BM112-HCEB  | 4.325V                        | 0.1V   | 2.58V                            | 0.12V   | 0.150V                                   | -0.145V                                  | Yes                   | (2)                    | PAHXX/<br>CMXX |
| BM112-SAEA  | 4.350V                        | 0.1V   | 2.33V                            | 0.10V   | 0.150V                                   | -0.120V                                  | No                    | (1)                    | PCSXX/<br>CAXX |
| BM112-TAEA  | 4.375V                        | 0.1V   | 2.34V                            | 0.10V   | 0.150V                                   | -0.120V                                  | No                    | (1)                    | PCTXX/<br>CTXX |

**Table 2. The detail of delay time combination (1)to(3)**

(@ 25℃)

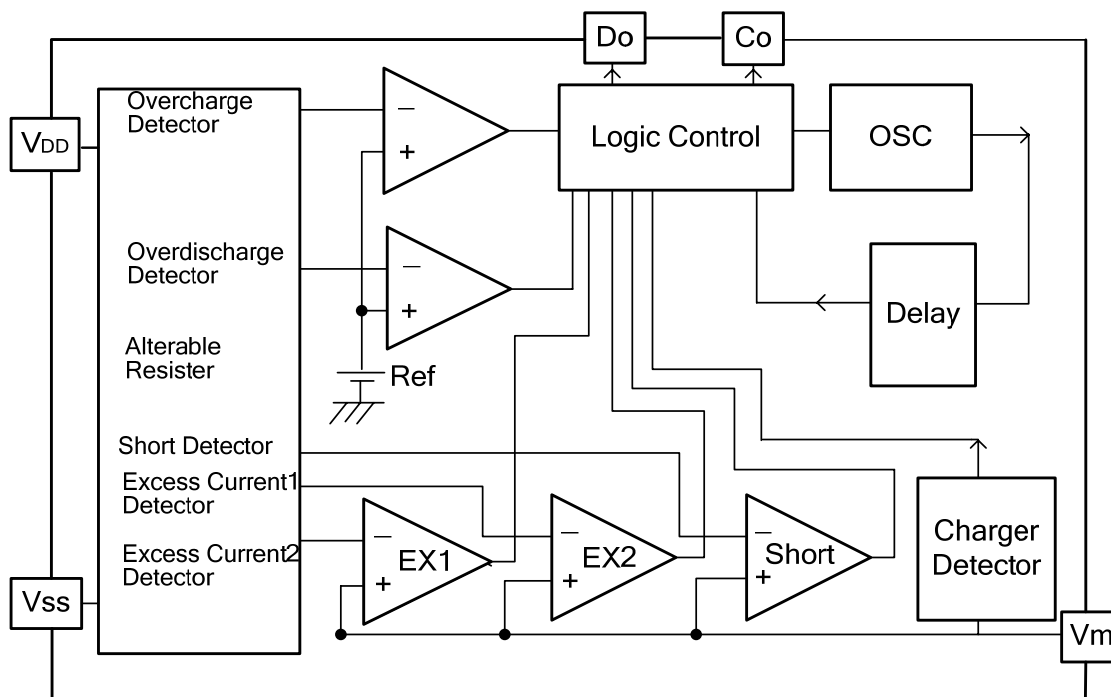
| Delay time combination | Output Delay Of Overcharge<br>Tvdet1 | Abnormal Charge Delay Time<br>Tab | Output Delay Of Over-discharge<br>Tvdet2 | Output Delay Of Excess Current 1<br>Tvdet3 |
|------------------------|--------------------------------------|-----------------------------------|--|--|
| (1)                    | 300~900ms<br>Typ:600ms               | 9~27ms<br>Typ:18ms                | 36~108ms<br>Typ:72ms                     | 5~15ms<br>Typ:10ms                         |
| (2)                    | 300~900ms<br>Typ:600ms               | 5~15ms<br>Typ:10ms                | 36~108ms<br>Typ:72ms                     | 5~15ms<br>Typ:10ms                         |
| (3)                    | 0.55~1.65s<br>Typ:1.1s               | 5~15ms<br>Typ:10ms                | 36~108ms<br>Typ:72ms                     | 5~15ms<br>Typ:10ms                         |

**Table 3. The detail of delay time combination (1)'to(3)'**

(@ -30℃~80℃)

| Delay time combination | Output Delay Of Overcharge<br>Tvdet1 | Abnormal Charge Delay Time<br>Tab | Output Delay Of Over-discharge<br>Tvdet2 | Output Delay Of Excess Current 1<br>Tvdet3 |
|------------------------|--------------------------------------|-----------------------------------|--|--|
| (1)'                   | 250~1000ms<br>Typ:600ms              | 7.5~30ms<br>Typ:18ms              | 30~120ms<br>Typ:72ms                     | 4~16ms<br>Typ:10ms                         |
| (2)'                   | 250~1000ms<br>Typ:600ms              | 3~18ms<br>Typ:10ms                | 30~120ms<br>Typ:72ms                     | 3~18ms<br>Typ:10ms                         |
| (3)'                   | 0.55~1.65s<br>Typ:1.1s               | 3~18ms<br>Typ:10ms                | 30~120ms<br>Typ:72ms                     | 3~18ms<br>Typ:10ms                         |

## Block Diagram

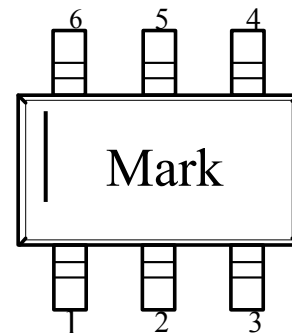


## Pin Description

**Table 4. SOT-23-6L**

| Pin | Symbol          | Description                           |
|-----|-----------------|---------------------------------------|
| 1   | D <sub>O</sub>  | Over-discharge detection, CMOS output |
| 2   | V <sub>M</sub>  | Connected to charger's negative pin   |
| 3   | C <sub>O</sub>  | Overcharge detection, CMOS output     |
| 4   | NC              | No connection                         |
| 5   | V <sub>DD</sub> | Power supply                          |
| 6   | V <sub>SS</sub> | Ground                                |

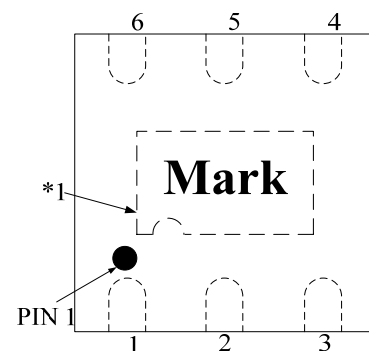
**SOT-23-6 (Top Side)**



**Table 5. DFNWB2\*2-6L**

| Pin | Symbol          | Description                           |
|-----|-----------------|---------------------------------------|
| 1   | C <sub>O</sub>  | Over-charge detection, CMOS output    |
| 2   | V <sub>M</sub>  | Connected to charger's negative pin   |
| 3   | D <sub>O</sub>  | Over-discharge detection, CMOS output |
| 4   | V <sub>SS</sub> | Ground                                |
| 5   | V <sub>DD</sub> | Power supply                          |
| 6   | NC              | No connection                         |
| *1  | NC              | No Connection                         |

**DFNWB2\*2-6L (Top Side)**



Notes: Overcharge delay, excess-current delay and over-discharge delay will all be shorten with the D<sub>P</sub> connected to V<sub>DD</sub>. In normal condition, D<sub>P</sub> should be connected to V<sub>SS</sub> or floating. In the package of DFNWB2\*2-6L, Pin1 to pin6 are the lead connection.

## Function Description

### Normal Condition:

$V_{DD}$  is between the Over-discharge Detection Threshold ( $V_{det2}$ ) and Overcharge Detection Threshold ( $V_{det1}$ ) and the  $V_M$  pad voltage is between Charger Detection Voltage ( $V_{cha}$ ) and the Excess Current 1 Threshold Voltage ( $V_{det3}$ ), therefore the outputs of  $D_O$  pad and  $C_O$  pad are high and the MOSFETs of charge and discharge are all on. Charging and discharging can be carried out freely.

### Overcharge Condition:

When  $V_{DD}$  increases and passes  $V_{det1}$  during charging under the normal condition, the output of  $C_O$  pad will change from high to low after Overcharge Detection Delay Time ( $T_{vdet1}$ ), turning off the charging control FET.

If, within  $T_{vdet1}$ ,  $V_{DD}$  becomes lower than  $V_{det1}$  and stays for duration shorter than Overcharge Reset Delay Time ( $T_{reset}$ ) before rising up over  $V_{det1}$  again, this type of instantaneous falling of  $V_{DD}$  is ignored. Otherwise, if the time  $V_{DD}$  stays lower than  $V_{det1}$  is longer than  $T_{reset}$ , the timing related to  $T_{vdet1}$  shall be reset.

### Abnormal Charge Current Condition:

If the  $V_M$  pin voltage falls below the Charger Detection Voltage ( $V_{cha}$ ) during charging under normal condition and it continues for the Abnormal Charge Current Delay Time ( $T_{ab}$ ) or longer, the charging control FET turns off and charging stops. This action is called the abnormal charge current detection.

Abnormal charge current detection works when the  $D_O$  pin voltage is "H" and the  $V_M$  pin voltage falls below the Charger Detection Voltage ( $V_{cha}$ ). To an over-discharged battery, only when charging makes the battery voltage higher than the Over-discharge Detection Threshold ( $V_{DT}$ ), the Abnormal Charge Current Detection can act. Abnormal charge current state is released, once the voltage difference between  $V_M$  pin and  $V_{SS}$  pin becomes less than the Abnormal Charge Current Detection Threshold Voltage ( $V_{AB}$ ) value.

### Overcharge Protection Release Condition:

The charging state can be reset and the output of  $C_O$  becomes high when  $V_{DD}$  becomes lower than the Overcharge Release Voltage ( $V_{rel1}$ ) and stays longer than Overcharge Release Delay Time ( $T_{vrel1}$ ).

When a load is connected to  $V_{DD}$  after a charger is disconnected from the battery pack, while the  $V_{DD}$  level is lower than  $V_{det1}$ , the output of  $C_O$  becomes high.

### Over-discharge Condition:

While discharging, after  $V_{DD}$  lowers below Over-discharge Detection Threshold ( $V_{det2}$ ),  $D_O$  pad goes low after Over-discharge Detection Delay Time ( $T_{vdet2}$ ). The  $D_O$  pad would switch off the discharging control FET and stop discharging.

### Over-discharge Protection Release Condition:

When IC is in over-discharge condition, if a charger is connected to the battery pack, and the battery supply voltage becomes higher than  $V_{det2}$ , and  $V_M$  is lower than Charger Detection Voltage ( $V_{cha}$ ),  $D_O$  pad becomes high, allowing discharging action.

IC without Auto wake up function: The discharging state also can be reset and the output of  $D_O$  becomes high when  $V_{DD}$  becomes higher than the Over-discharge Release Voltage ( $V_{rel2}$ ),  $V_M$  is between  $V_{det3}$  and  $V_{cha}$ , and stays longer than Release Delay Time ( $T_{vrel2}$ ).

IC with Auto wake up function: The discharging state also can be reset and the output of  $D_O$  becomes high when  $V_{DD}$  becomes higher than the Over-discharge Release Voltage ( $V_{rel2}$ ),  $V_M$  is between  $V_{cha}$  and  $V_{DD}$ , and stays longer than Release Delay Time ( $T_{vrel2}$ ).

When a charger is connected from the battery pack, while the  $V_{DD}$  level is lower than  $V_{det2}$ , the battery pack makes charger current allowable through the external diode.

**Charger Detect Condition:**

When a battery in the over-discharge condition is connected to a charger and provided that the  $V_M$  pin voltage is lower than the Charger Detection Voltage ( $V_{cha}$ ), IC releases the over-discharge condition and turns on the discharging control FET as the battery voltage becomes higher than the Over-discharge Detection Voltage ( $V_{det2}$ ) since the charger detection function works. This action is called charger detection.

When a battery in the over-discharge condition is connected to a charger and provided that the  $V_M$  pin voltage is between the Charger Detection Voltage ( $V_{cha}$ ) and Excess Current 1

Threshold Voltage ( $V_{det3}$ ), IC releases the over-discharge condition when the battery voltage reaches the Over-discharge Release Voltage ( $V_{rel2}$ ) or higher.

**Excess Current 1 Protection:**

During discharging, the current varies with load, and  $V_M$  increases with the rise of the discharging current. Once  $V_M$  rises up to the Excess Current 1 Threshold Voltage ( $V_{det3}$ ) or higher and stays longer than the Excess Current 1 Delay Time ( $T_{vdet3}$ ), Do pad switches to low, turning off the discharging control FET. After that excess current state is removed, i.e.  $V_M < V_{det3}$ , and the circuit recovers to normal condition.

**Excess Current 2 Protection:**

During discharging, the current varies with load, and  $V_M$  increases with the rise of the discharging current. Once  $V_M$  rises up to Excess Current 2 Threshold Voltage ( $V_{det4}$ ) or higher, and stays longer than Excess Current 2 Delay Time ( $T_{vdet4}$ ), Do pad switches to low, turning off the discharging control FET. After that excess current state is removed, i.e.  $V_M < V_{det3}$ , and the circuit recovers to normal condition.

**Short Circuit Protection:**

This function has the same principle as the excess current protection. But, the delay time  $T_{short}$  is far shorter than  $T_{vdet3}$  and  $T_{vdet4}$ , and the threshold  $V_{short}$  is far higher than  $V_{det3}$  and  $V_{det4}$ . When the circuit is shorted,  $V_M$  increases rapidly. Once  $V_M \geq V_{short}$ , Do pad switches to low, turning off the discharging control FET. After the short circuit state is removed, i.e.  $V_M < V_{det3}$ , the circuit recovers to the normal condition. The short circuit peak current is related to  $V_{short}$  and the ON resistance of the two FETs in series. Output types of Co and Do are CMOS level.

**0V battery charge function**

This function is used to recharge the connected battery whose voltage is 0V due to the self-discharge. When the 0 V battery charge starting charger voltage ( $V_{0cha}$ ) or higher is applied between P+ and P- pins (see the Typical Application Circuits of Page1) by connecting a charger, the charging control FET gate is fixed to  $V_{DD}$  pin voltage. When the voltage between the gate and source of the charging control FET becomes equal to or higher than the turn-on voltage by the charger voltage, the charging control FET turns on to start charging. At this time, the discharging control FET is off and the charging current flows through the internal parasitic diode in the discharging control FET. When the battery voltage becomes equal to or higher than the Over-discharge Detection Threshold ( $V_{det2}$ ), the IC enters the normal condition.

# Electrical Characteristics <sup>1\*</sup>

(T<sub>OPT</sub>=25°C unless otherwise specified)

| Symbol  | Item   | Conditions                                       | Min.          | TYP.            | Max.          | Unit |
|---|--|--|---------------|-----------------|---------------|------|
| <b>DETECTION VOLTAGE AND DELAY TIME</b>                     |  |  |               |                 |               |      |
| Vdet1 <sup>2*</sup>   | Overcharge Threshold<br>4.200~4.400V, Step 5mV         | 25°C   | Vdet1 – 0.025 | Vdet1           | Vdet1 + 0.025 | V    |
| Vrel1 <sup>3*</sup>   | Release Voltage For Overcharge<br>Detection            |  | VDET1 –1.3Vhc | VDET1–Vhc       | VDET1 –0.7Vhc | V    |
| Vdet2 <sup>2*</sup>   | Over-discharge Threshold 2.2~2.4V                      | Detect falling edge of supply<br>voltage         | Vdet2 – 0.075 | Vdet2           | Vdet2 + 0.075 | V    |
| Vrel2 <sup>3*</sup>   | Release Voltage For Over-discharge<br>Detection        |  | VDET2+0.7Vhd  | VDET2+Vhd       | VDET2+1.3Vhd  | V    |
| Vdet3   | Excess Current 1 Threshold                             | V <sub>DD</sub> = 3.30V                          | Vdet3-0.015   | Vdet3           | Vdet3+0.015   | V    |
| Vdet4   | Excess Current 2 Threshold                             | V <sub>DD</sub> = 3.30V                          | 0.35          | 0.40            | 0.45          | V    |
| Vshort  | Short Protection Voltage                               | V <sub>DD</sub> = 3.30V                          | 0.65          | 0.80            | 0.95          | V    |
| Vcha  | Charger Detection<br>(Abnormal Charge)                 |  | Vcha -0.030   | Vcha            | Vcha +0.030   | V    |
| V0cha   | 0V Battery Charge Starting<br>Charger Voltage          | Applied for 0V battery<br>charge function        | 1.2           |                 |               | V    |
| Tvrel1  | Overcharge ReleaseDelay Time                           | V <sub>DD</sub> = 4.4V→4.0V                      | 8             | 25              | 40            | ms   |
| Treset  | Overcharge Reset Delay Time                            | V <sub>DD</sub> = 4.4V→4.0V→4.4V                 | 5             | 23              | 38            | ms   |
| Tvrel2  | Over-discharge Release Delay Time                      | V <sub>DD</sub> = 2.0V→3.0V, V <sub>M</sub> = 0V | 1.1           | 2.2             | 3.3           | ms   |
| Tvdet4  | Output Delay Of Excess Current 2                       | V <sub>DD</sub> = 3.30V                          | 0.6           | 1.1             | 1.6           | ms   |
| Tshort  | Output Delay Of Short Protection                       | V <sub>DD</sub> = 3.30V                          | 70            | 140             | 210           | us   |
| <b>OUTPUT VOLTAGE AND V<sub>M</sub> INTERNAL RESISTANCE</b> |  |  |               |                 |               |      |
| V <sub>COL</sub>  | CO Pin L Voltage                                       | I <sub>OL</sub> =50uA, V <sub>DD</sub> =4.4V     | 0.15          | 0.20            | 0.25          | V    |
| V <sub>COH</sub>  | CO Pin H Voltage                                       | I <sub>OH</sub> =-50uA, V <sub>DD</sub> =3.9V    | 3.75          | 3.70            | 3.65          | V    |
| V <sub>DOL</sub>  | DO Pin L Voltage                                       | I <sub>OL</sub> =50uA, V <sub>DD</sub> =2.0V     | 0.05          | 0.07            | 0.09          | V    |
| V <sub>DOH</sub>  | DO Pin H Voltage                                       | I <sub>OH</sub> =-50uA, V <sub>DD</sub> =3.9V    | 3.85          | 3.83            | 3.81          | V    |
| R <sub>VMD</sub>  | Resistance between V <sub>M</sub> and V <sub>DD</sub>  | V <sub>DD</sub> =2.0V, V <sub>M</sub> =0V        | 100           | 300             | 900           | kΩ   |
| R <sub>VMS</sub>  | Resistance between V <sub>M</sub> and V <sub>SS</sub>  | V <sub>DD</sub> =3.3V, V <sub>M</sub> =1V        | 60            | 130             | 300           | kΩ   |
| <b>OPERRATION VOLTAGE AND CURRENT CONSUMPTION</b>           |  |  |               |                 |               |      |
| V <sub>DD</sub>   | Operating Input Voltage                                | V <sub>DD</sub> -V <sub>SS</sub>                 | 1.6           | V <sub>DD</sub> | 8             | V    |
| V <sub>M</sub>  | Operating Input Voltage                                | V <sub>DD</sub> -V <sub>M</sub>                  | 1.5           | --              | 28            | V    |
| I <sub>DD</sub>   | Supply Current   | V <sub>DD</sub> = 3.9V, V <sub>M</sub> = 0V      |               | 4.0             | 7.0           | uA   |
| I <sub>STANDBY</sub>  | Standby Current (for products<br>without Auto wake up) | V <sub>DD</sub> = 2.0V, V <sub>M</sub> = 0V→2.0V |               | 0.1             | 0.7           | uA   |
| I <sub>STANDBY4*</sub>                                      | Standby Current (for products with<br>Auto wake up)    | V <sub>DD</sub> = 2.0V                           |               | 1.8             | 3.5           | uA   |

1\* The Electrical parameters for this temperature range is guaranteed by design, not tested in production.

2\* See “Selection Guide” section.

3\* VDET1 and VDET2 are the Overcharge and Over-discharge threshold voltage of actual testing.

4\* Vhc and Vhd are the Overcharge and Over-discharge hysteresis voltage.



Electrical Characteristics <sup>1\*</sup>(T<sub>OPT</sub> = -30°C~80°C unless otherwise specified)

| Symbol  | Item   | Conditions   | Min.                                   | TYP.                                | Max.                                   | Unit |
|---|--|--|--|-------------------------------------|--|------|
| DETECTION VOLTAGE AND DELAY TIME                      |  |  |  |                                     |  |      |
| V <sub>det1</sub> <sup>2*</sup>                       | Overcharge Threshold<br>4.200~4.400V, Step 5mV                             | -30~80°C   | V <sub>det1</sub> - 0.050              | V <sub>det1</sub>                   | V <sub>det1</sub> + 0.050              | V    |
| V <sub>rel1</sub> <sup>3*</sup>                       | Release Voltage For Overcharge<br>Detection V <sub>hc</sub> =0.1V~0.3V     |  | V <sub>DET1</sub> - 1.4V <sub>hc</sub> | V <sub>DET1</sub> - V <sub>hc</sub> | V <sub>DET1</sub> - 0.6V <sub>hc</sub> | V    |
| V <sub>det2</sub> <sup>2*</sup>                       | Over-discharge Threshold<br>2.2~2.4V                                       | Detect falling edge of supply<br>voltage           | V <sub>det2</sub> - 0.1                | V <sub>det2</sub>                   | V <sub>det2</sub> + 0.1                | V    |
| V <sub>rel2</sub> <sup>3*</sup>                       | Release Voltage For Over-discharge<br>Detection V <sub>hd</sub> =0.1V~0.3V |  | V <sub>DET2</sub> + 0.6V <sub>hd</sub> | V <sub>DET2</sub> + V <sub>hd</sub> | V <sub>DET2</sub> + 1.4V <sub>hd</sub> | V    |
| V <sub>det3</sub>                                     | Excess Current 1 Threshold   | V <sub>DD</sub> = 3.30V                            | V <sub>det3</sub> - 0.020              | V <sub>det3</sub>                   | V <sub>det3</sub> + 0.020              | V    |
| V <sub>det4</sub>                                     | Excess Current 2 Threshold   | V <sub>DD</sub> = 3.30V                            | 0.27                                   | 0.40                                | 0.53                                   | V    |
| V <sub>short</sub>                                    | Short Protection Voltage   | V <sub>DD</sub> = 3.30V                            | 0.50                                   | 0.80                                | 1.30                                   | V    |
| V <sub>cha</sub>                                      | Charger Detection<br>(Abnormal Charge)                                     |  | V <sub>cha</sub> - 0.040               | V <sub>cha</sub>                    | V <sub>cha</sub> + 0.040               | V    |
| V <sub>0cha</sub>                                     | 0V battery Charge Starting<br>Charger Voltage                              | Applied for 0V battery<br>charge function          | 1.2                                    |                                     |  | V    |
| T <sub>vrel1</sub>                                    | Overcharge Release Delay Time  | V <sub>DD</sub> = 4.4V → 4.0V                      | 5                                      | 25                                  | 42                                     | ms   |
| T <sub>reset</sub>                                    | Overcharge Reset Delay Time  | V <sub>DD</sub> = 4.4V → 4.0V → 4.4V               | 3                                      | 23                                  | 40                                     | ms   |
| T <sub>vrel2</sub>                                    | Over-discharge Release Delay<br>Time                                       | V <sub>DD</sub> = 2.0V → 3.0V, V <sub>M</sub> = 0V | 0.9                                    | 2.2                                 | 3.6                                    | ms   |
| T <sub>vdet4</sub>                                    | Output Delay Of Excess Current 2   | V <sub>DD</sub> = 3.30V                            | 0.45                                   | 1.1                                 | 1.8                                    | ms   |
| T <sub>short</sub>                                    | Output Delay Of Short Protection   | V <sub>DD</sub> = 3.30V                            | 55                                     | 140                                 | 230                                    | us   |
| OUTPUT VOLTAGE AND V <sub>M</sub> INTERNAL RESISTANCE |  |  |  |                                     |  |      |
| V <sub>COL</sub>                                      | CO Pin L Voltage   | I <sub>OL</sub> = 50uA, V <sub>DD</sub> = 4.4V     | 0.10                                   | 0.20                                | 0.30                                   | V    |
| V <sub>COH</sub>                                      | CO Pin H Voltage   | I <sub>OH</sub> = -50uA, V <sub>DD</sub> = 3.9V    | 3.80                                   | 3.70                                | 3.60                                   | V    |
| V <sub>DOL</sub>                                      | DO Pin L Voltage   | I <sub>OL</sub> = 50uA, V <sub>DD</sub> = 2.0V     | 0.03                                   | 0.07                                | 0.11                                   | V    |
| V <sub>DOH</sub>                                      | DO Pin H Voltage   | I <sub>OH</sub> = -50uA, V <sub>DD</sub> = 3.9V    | 3.87                                   | 3.83                                | 3.79                                   | V    |
| R <sub>VMD</sub>                                      | Resistance Between V <sub>M</sub> And V <sub>DD</sub>                      | V <sub>DD</sub> = 2.0V, V <sub>M</sub> = 0V        | 78                                     | 300                                 | 1310                                   | kΩ   |
| R <sub>VMS</sub>                                      | Resistance Between V <sub>M</sub> And V <sub>SS</sub>                      | V <sub>DD</sub> = 3.3V, V <sub>M</sub> = 1V        | 40                                     | 130                                 | 400                                    | kΩ   |
| OPERATION VOLTAGE AND CURRENT CONSUMPTION             |  |  |  |                                     |  |      |
| V <sub>DD</sub>                                       | Operating Input Voltage  | V <sub>DD</sub> - V <sub>SS</sub>                  | 1.6                                    | V <sub>DD</sub>                     | 8                                      | V    |
| V <sub>M</sub>  | Operating Input Voltage  | V <sub>DD</sub> - V <sub>M</sub>                   | 1.5                                    | --                                  | 28                                     | V    |
| I <sub>DD</sub>                                       | Supply Current   | V <sub>DD</sub> = 3.9V, V <sub>M</sub> = 0V        |  | 4.0                                 | 8.0                                    | uA   |
| I <sub>STANDBY</sub>                                  | Standby Current (for products with<br>power-down function)                 | V <sub>DD</sub> = 2.0V, V <sub>M</sub> = 0V → 2.0V |  | 0.1                                 | 1                                      | uA   |
| I <sub>STANDBY</sub>                                  | Standby Current (for products<br>without power-down function)              | V <sub>DD</sub> = 2.0V                             |  | 1.8                                 | 4.0                                    | uA   |

1\* The Electrical parameters for this temperature range is guaranteed by design, not tested in production.

2\* See "Selection Guide" section.

3\* V<sub>DET1</sub> and V<sub>DET2</sub> are the overcharge and over-discharge threshold voltage of actual testing.

4\* V<sub>hc</sub> and V<sub>hd</sub> are the Overcharge and Over-discharge hysteresis voltage.

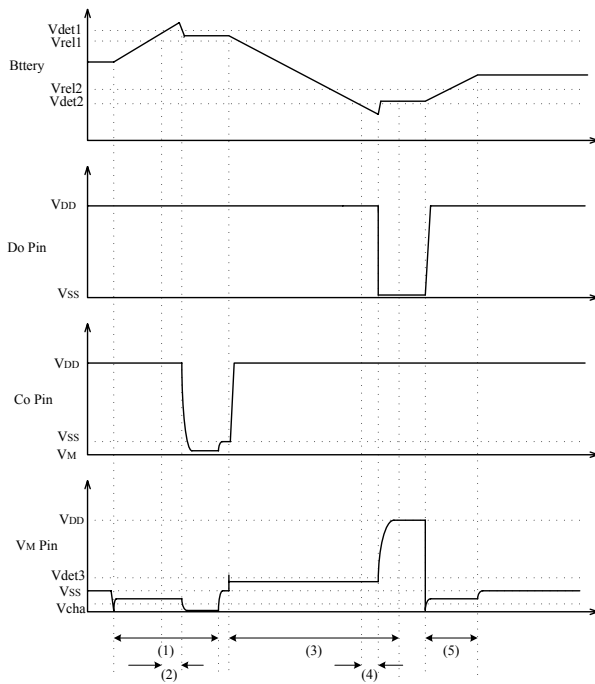
**Absolute Maximum Ratings** ( $T_a = 25\text{ }^{\circ}\text{C}$   $V_{SS} = 0\text{ V}$ )

| Symbol    | Item                        | Ratings                          | Unit               |
|-----------|-----------------------------|----------------------------------|--------------------|
| $V_{DD}$  | Supply Voltage              | -0.3 to 8                        | V                  |
| $V_M$     | $V_M$ Pin Input Voltage     | $V_{DD} - 28$ to $V_{DD} + 0.3$  | V                  |
| $V_{CO}$  | Co Pin Output Voltage       | $V_{DD} - 28$ to $V_{DD} + 0.3$  | V                  |
| $V_{DO}$  | Do Pin Output Voltage       | $V_{SS} - 0.3$ to $V_{DD} + 0.3$ | V                  |
| $P_d$     | Power Dissipation           | 150                              | mW                 |
| $T_{opt}$ | Operating Temperature Range | -30 to 80                        | $^{\circ}\text{C}$ |
| $T_{stg}$ | Storage Temperature Range   | -55 to 125                       | $^{\circ}\text{C}$ |

Caution: These values must not be exceeded under any conditions.

## Operation Timing Chart (1)

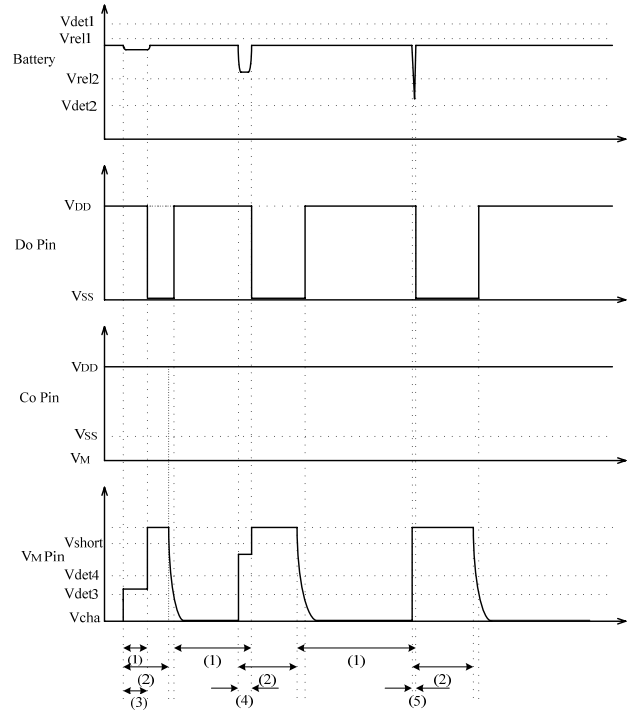
### Overcharge/Over-discharge Detection



- (1) Charger connected
- (2) Overcharge Detection Delay Time (Tvdet1)
- (3) Load connected
- (4) Over-discharge Detection Delay Time (Tvdet2)
- (5) Normal charging

## Operation Timing Chart (2)

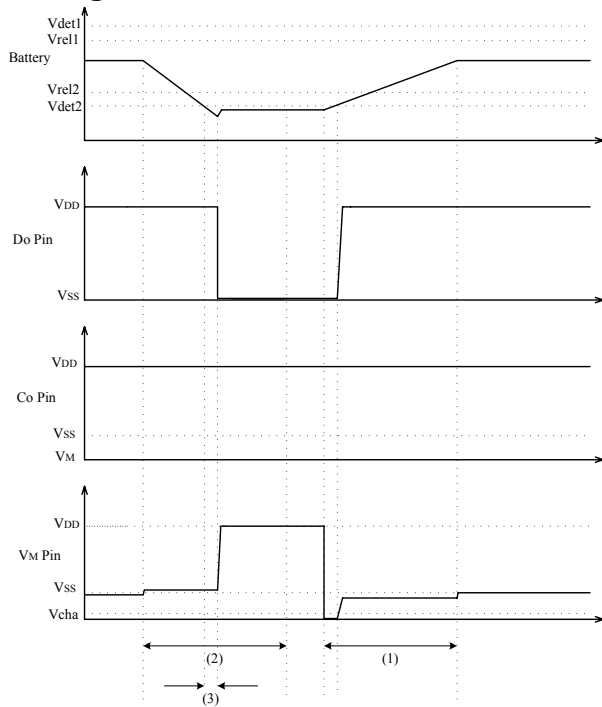
### Excess Current and Short Protection



- (1) Normal condition
- (2) Load connection
- (3) Excess Current 1 Delay Time (Tvdet3)
- (4) Excess Current 2 Delay Time (Tvdet4)
- (5) Short Circuit Delay Time (Tshort)

## Operation Timing Chart (3)

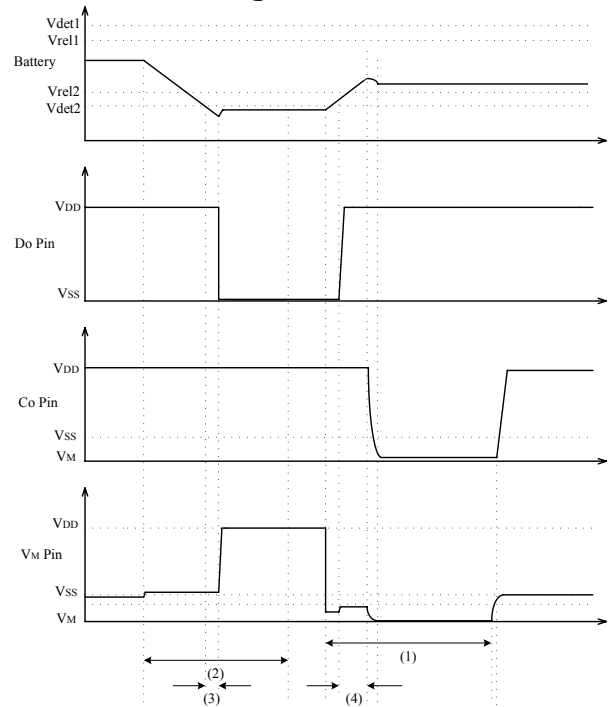
### Charger Connection Detection



- (1) Charger connection
- (2) Load connection
- (3) Over-discharge Detection Delay (Tvdet2)

## Operation Timing Chart (4)

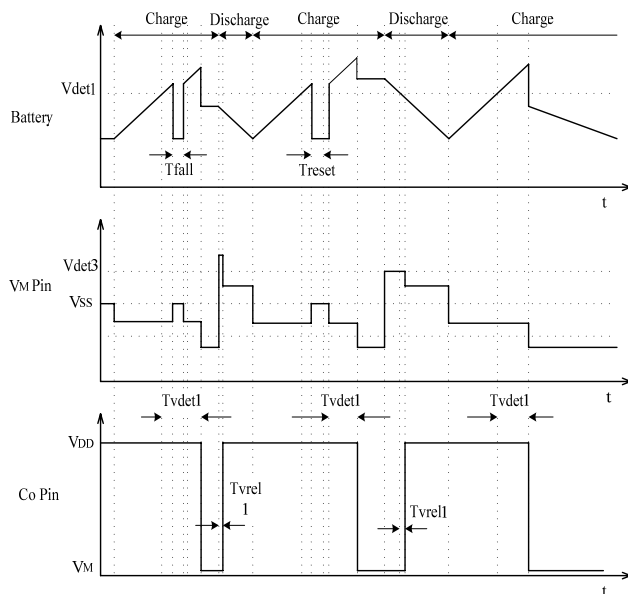
### Abnormal Charge Current Detection



- (1) Charger connection
- (2) Load connection
- (3) Over-discharge Detection Delay Time (Tvdet2)
- (4) Abnormal Charging Current Detection Delay Time

## Operation Timing Chart (5)

### Overcharge, Timer Reset for Overcharge



### Test Circuits

#### (1) Overcharge detection voltage and overcharge release voltage

##### Test circuit 1

The Overcharge Detection Voltage ( $V_{det1}$ ) is the voltage between  $V_{DD}$  and  $V_{SS}$  to which when  $V_1$  increases and keeps the condition for overcharge delay time,  $V_{co}$  changes from "H" to "L". The Overcharge Release Voltage ( $V_{rel1}$ ) is the voltage between  $V_{DD}$  and  $V_{SS}$  to which when  $V_1$  decreases,  $V_{co}$  changes from "L" to "H".

#### (2) Over-discharge detection voltage and over-discharge release voltage

##### Test circuit 1

The Over-discharge Detection Voltage ( $V_{det2}$ ) is the voltage between  $V_{DD}$  and  $V_{SS}$  to which when  $V_1$  decreases and keep the condition for over-discharge delay time,  $V_{DO}$  changes from "H" to "L". The over-discharge Release Voltage ( $V_{rel2}$ ) is the voltage between  $V_{DD}$  and  $V_{SS}$  to which when  $V_1$  increases,  $V_{DO}$  changes from "L" to "H".

#### (3) Over current detection voltage and short circuit detection voltage

##### Test circuit 2

The Excess Current 1 Detection Voltage ( $V_{det3}$ ) is the voltage between  $V_M$  and  $V_{SS}$  to which when  $V_M$  increases within 10 us and keep the condition for Excess Current 1 Delay Time ( $T_{vdet3}$ ),  $V_{DO}$  changes from "H" to "L".

The Excess Current 2 Detection Voltage ( $V_{det4}$ ) is the voltage between  $V_M$  and  $V_{SS}$  to which when  $V_M$  increases within 10 us and keep the condition for Excess Current 2 Delay Time ( $T_{vdet4}$ ),  $V_{DO}$  changes from "H" to "L".

The Short Circuit Detection Voltage ( $V_{short}$ ) is the voltage between  $V_M$  and  $V_{SS}$  to which when  $V_M$  increases within 10us and keep the condition for Short Circuit Delay Time ( $T_{short}$ ),  $V_{DO}$  changes from "H" to "L".

#### (4) Charger detection voltage and abnormal charge current detection voltage

##### Test circuit 2

In the over-discharge condition, increase  $V_1$  gradually until it is between  $V_{det2}$  and  $V_{rel2}$ . The voltage between  $V_M$  and  $V_{SS}$  to which when  $V_2$  decreases,  $V_{DO}$  changes from "L" to "H", is the Charger Detection Voltage ( $V_{cha}$ ).

In the normal charging condition, the voltage between  $V_M$  and  $V_{SS}$  to which when  $V_2$  decreases,  $V_{co}$  changes from "H" to "L" is the abnormal charge current detection voltage. It has the same value as the Charger Detection Voltage ( $V_{cha}$ ).

#### (5) 0V battery charge starting charger voltage

##### Test circuit 2

Set  $V_1=V_2=0V$  and decrease  $V_2$  gradually. The voltage between  $V_{DD}$  and  $V_M$  when  $V_{co}$  goes "H" ( $V_{VM}+0.1V$  or higher ) is the 0V battery charge starting charger voltage.

#### (6) Normal operation current consumption and power down current consumption

##### Test circuit 2

Set  $V_1=3.5V$  and  $V_2=0V$  under normal condition, the current  $I_{DD}$  flowing through  $V_{DD}$  pin is the normal operation consumption current ( $I_{DD}$ ).

Set  $V_1=3.5V$  and  $V_2=0V$ , let IC work in normal condition, set  $V_1$  from 3.5V to 2.0V, then set  $V_2=2.0V$  under

over-discharge condition, the current  $I_{DD}$  flowing through  $V_{DD}$  pin is the power down current consumption ( $I_{STANDBY}$ ).

**(7) Overcharge detection (release) delay time and over-discharge detection (release) delay time**

**Test circuit 3**

If  $V_1$  increases to be  $V_{det1}$  or over  $V_{det1}$  and keeps the condition for some time,  $V_{CO}$  will change from "H" to "L".

The time is called overcharge detection delay time. It is used to judge whether overcharge happens indeed. If  $V_1$  decreases from  $V_{det1}$  or over  $V_{det1}$  to below  $V_{rel1}$ ,  $V_{CO}$  will change from "L" to "H". The difference between this time and  $T_{reset}$  is called overcharge release delay time.

If  $V_1$  decreases to be  $V_{det2}$  or below  $V_{det2}$  and keeps the condition for some time,  $V_{DO}$  will change from "H" to "L".

The time is called over-discharge detection delay time. It is used to judge whether over-discharge happens indeed. If  $V_1$  increases from  $V_{det2}$  or below  $V_{det2}$  to over  $V_{rel2}$  and keeps the condition for some time,  $V_{DO}$  will change from "L" to "H". The time is called over-discharge release delay time.

**(8) Over current detection delay time and short circuit detection delay time**

**Test circuit 3**

If  $V_2$  increases to be  $V_{det3}$  or over  $V_{det3}$  and keeps the condition for some time,  $V_{DO}$  will change from "H" to "L". The time is called over current 1 delay time. It is used to judge whether over current 1 happens indeed.

If  $V_2$  increases to be  $V_{det4}$  or over  $V_{det4}$  and keeps the condition for some time,  $V_{DO}$  will change from "H" to "L".

The time is called over current 2 delay time. It is used to judge whether over current 2 happens indeed.

If  $V_2$  increases to be  $V_{short}$  or over  $V_{short}$  and keeps the condition for some time,  $V_{DO}$  will change from "H" to "L".

The time is called short circuit delay time. It is used to judge whether short circuit happens indeed.

**(9) Co pin H resistance, Co pin L resistance**

**Test circuit 4**

Set  $V_1=3.9V$ ,  $V_2=0V$ ,  $I_{CO}=50\mu A$  (from Co to  $V_3$ ), K1 on and K2 off.  $(V_1-V_3)/I_{CO}$  is the Co pin H resistance.

Set  $V_1=4.4V$ ,  $V_2=0V$ ,  $I_{CO}=-50\mu A$  (from  $V_3$  to Co), K1 on and K2 off.  $V_3/I_{CO}$  is the Co pin L resistance.

**(10) Do pin H resistance, Do pin L resistance**

**Test circuit 4**

Set  $V_1=3.9V$ ,  $V_2=0V$ ,  $I_{DO}=50\mu A$  (from Do to  $V_4$ ), K1 off and K2 on.  $(V_1-V_4)/I_{DO}$  is the Do pin H resistance.

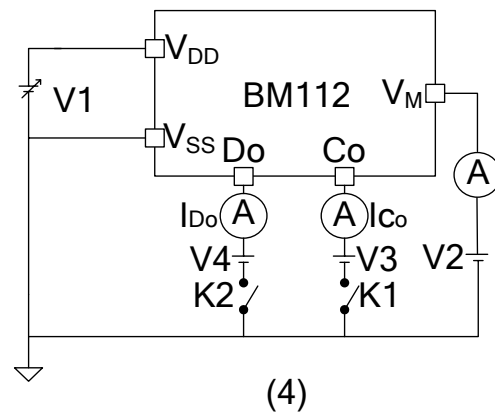
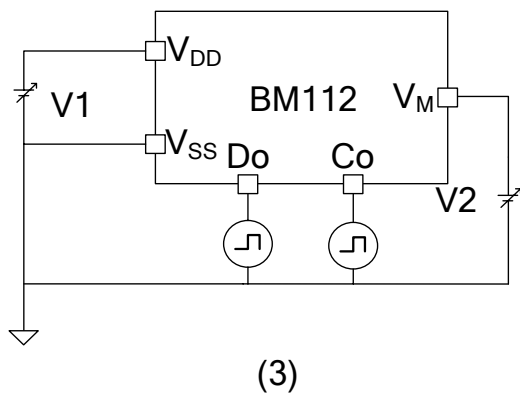
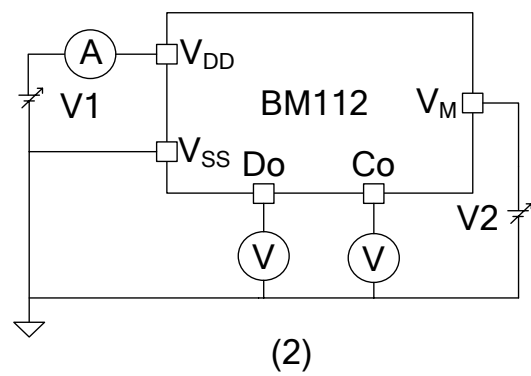
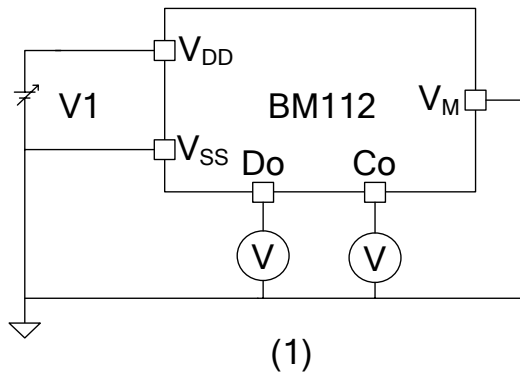
Set  $V_1=2.0V$ ,  $V_2=0V$  and  $I_{DO}=50\mu A$  (from  $V_4$  to Do), K1 off and K2 on.  $V_4/I_{DO}$  is the Do pin L resistance.

**(11) Internal resistance  $V_M-V_{DD}$  and  $V_M-V_{SS}$**

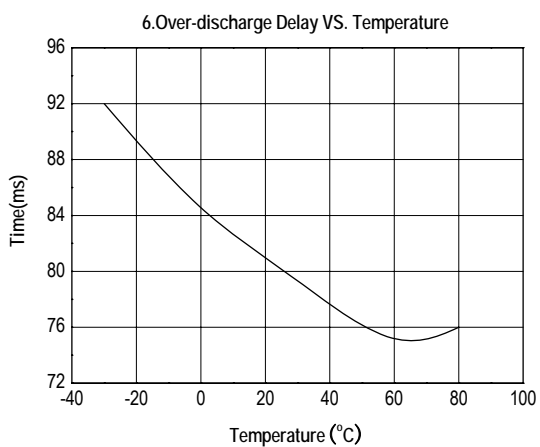
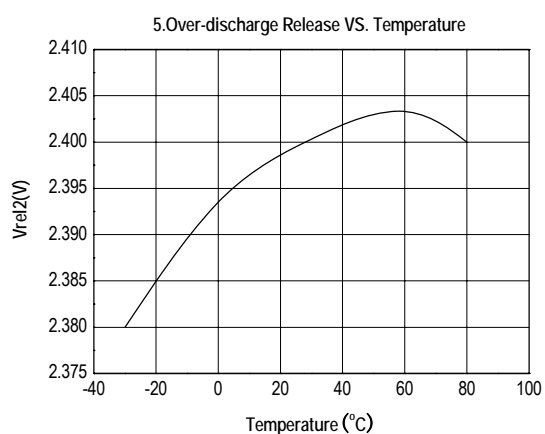
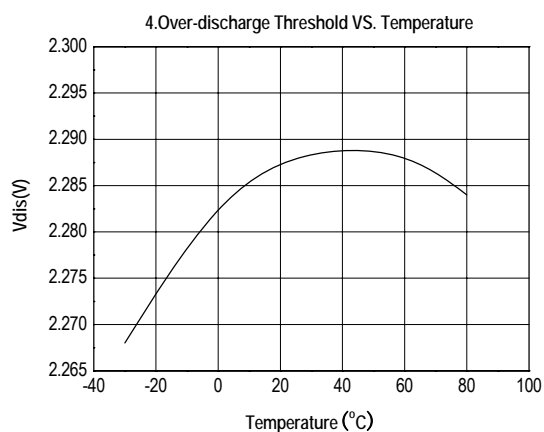
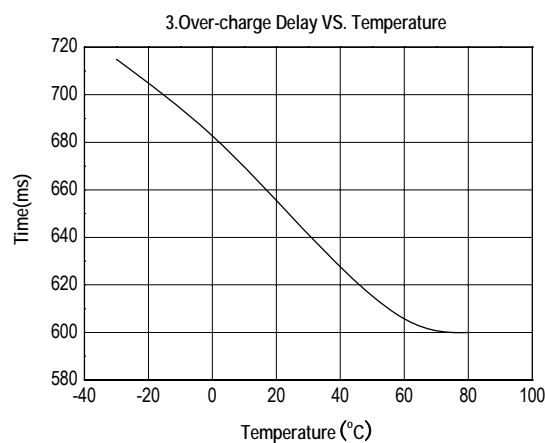
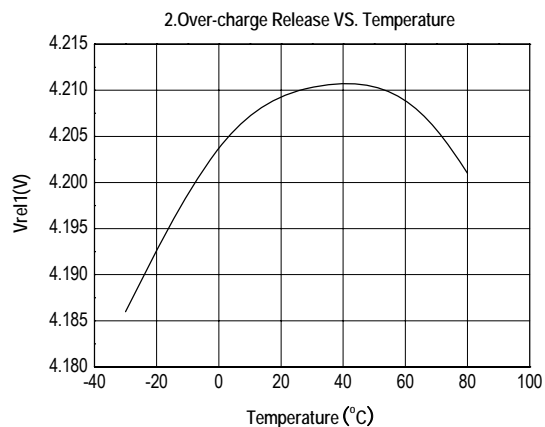
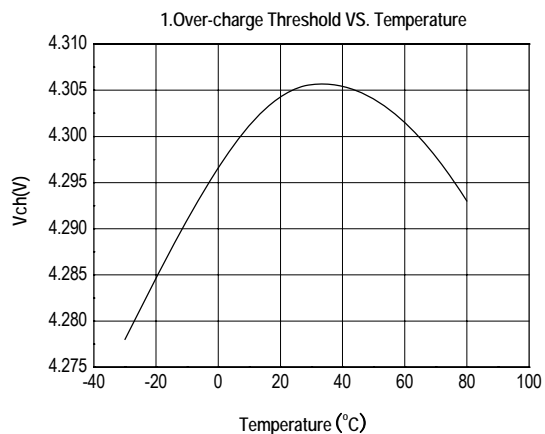
**Test circuit 4**

Set  $V_1=2.0V$ ,  $V_2=0V$ , K1 off and K2 off,  $V_1/I_{VM}$  is the internal resistance  $R_{VMD}$ .

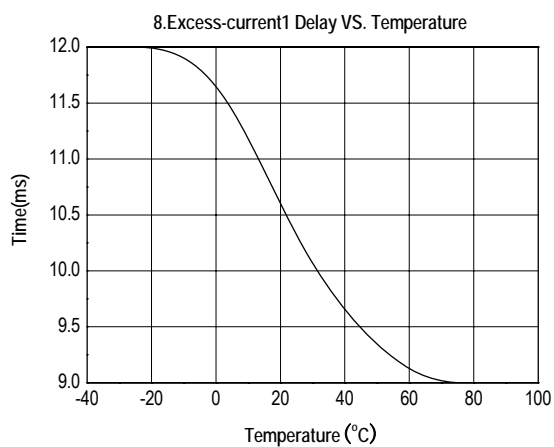
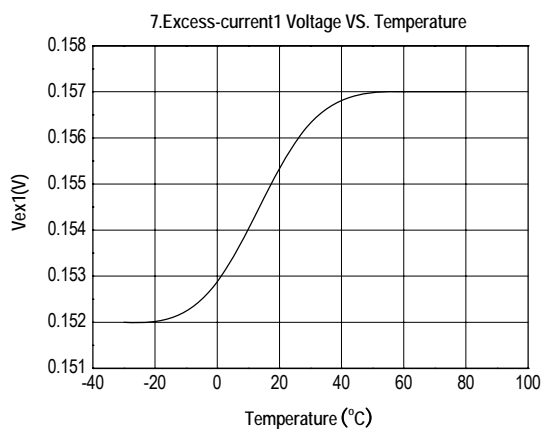
Set  $V_1=3.3V$ ,  $V_2=1V$ , K1 off and K2 off,  $V_2/I_{VM}$  is the internal resistance  $R_{VMS}$ .



## Typical Characteristic Charts

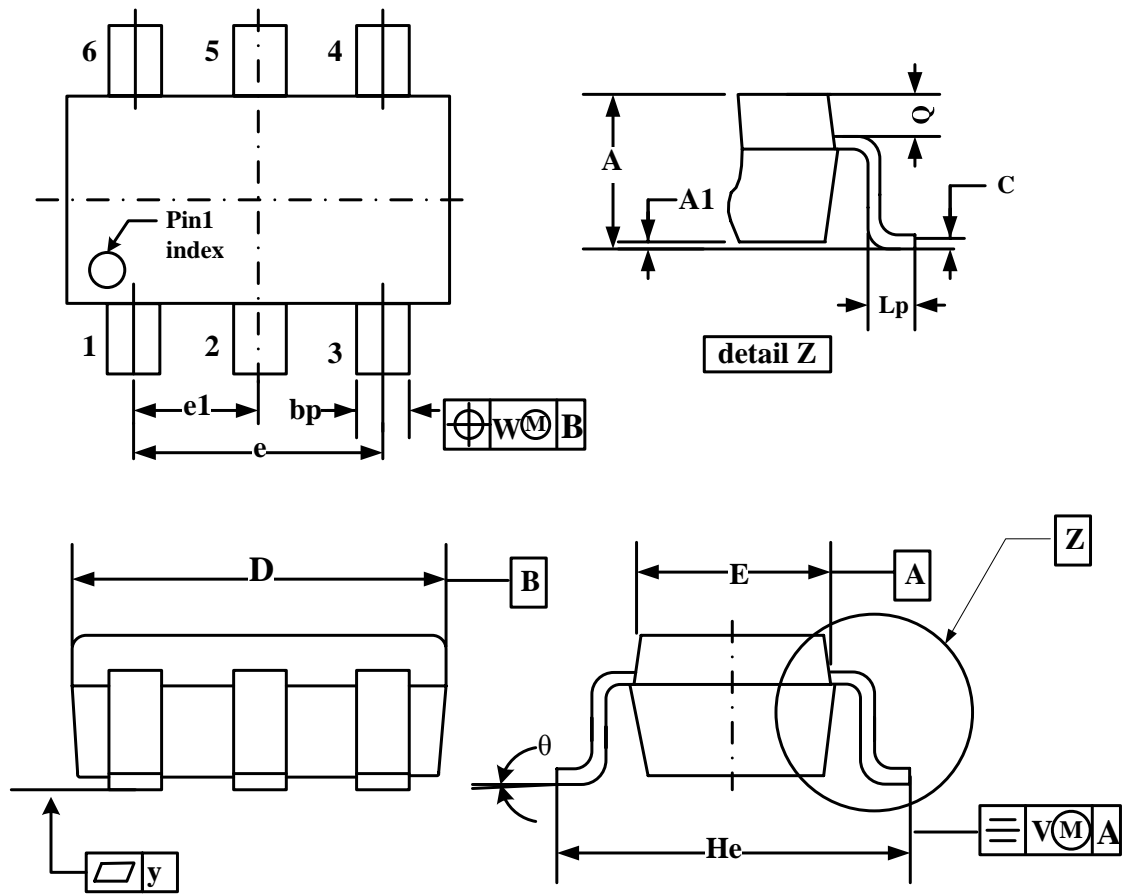






## Package Outline

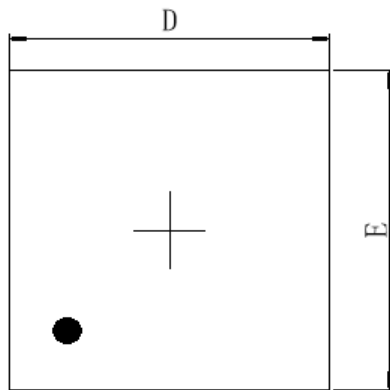
### SOT-23-6L



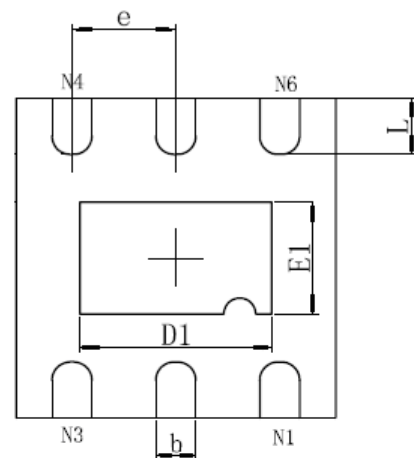
### Dimensions (mm)

| A   | A1   | bp   | c    | D   | E   | e   | e1   | He  | Lp  | Q    | v   | w   | y   | $\theta$ |
|-----|------|------|------|-----|-----|-----|------|-----|-----|------|-----|-----|-----|----------|
| 1.3 | 0.15 | 0.50 | 0.20 | 3.1 | 1.7 | 1.9 | 0.95 | 3.0 | 0.6 | 0.33 | 0.2 | 0.2 | 0.1 | 0°       |
| 1.0 | 0.03 | 0.35 | 0.10 | 2.7 | 1.3 |     |      | 2.5 | 0.2 | 0.23 |     |     |     | 10°      |

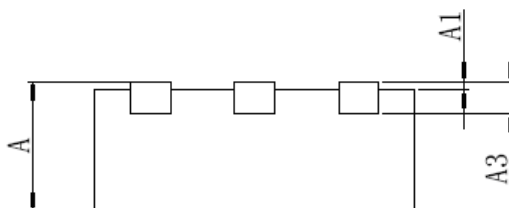
**DFNWB2\*2-6L**



**Top View**



**Bottom View**



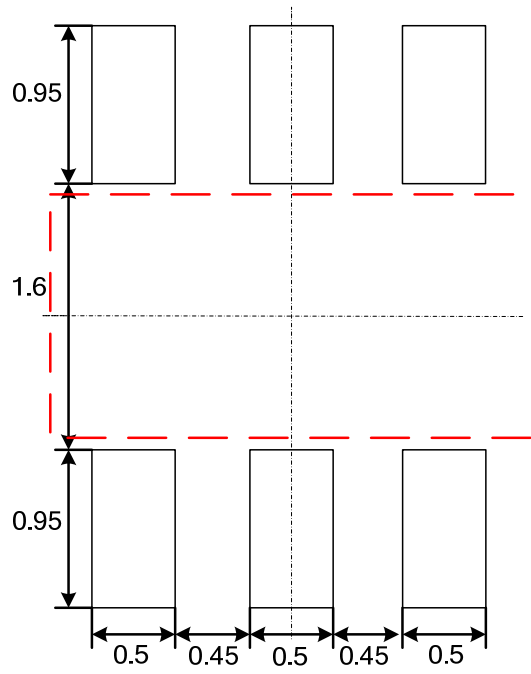
**Side View**

**Dimensions (mm)**

| A   | A1  | A3    | D    | E    | D1  | E1  | b   | e   | L   |
|-----|-----|-------|------|------|-----|-----|-----|-----|-----|
| 0.8 | 0   | 0.228 | 2.05 | 2.05 | 1.3 | 0.8 | 0.3 | 0.7 | 0.4 |
| 0.7 | 0.5 | 0.178 | 1.95 | 1.95 | 1.1 | 0.6 | 0.2 | 0.6 | 0.3 |

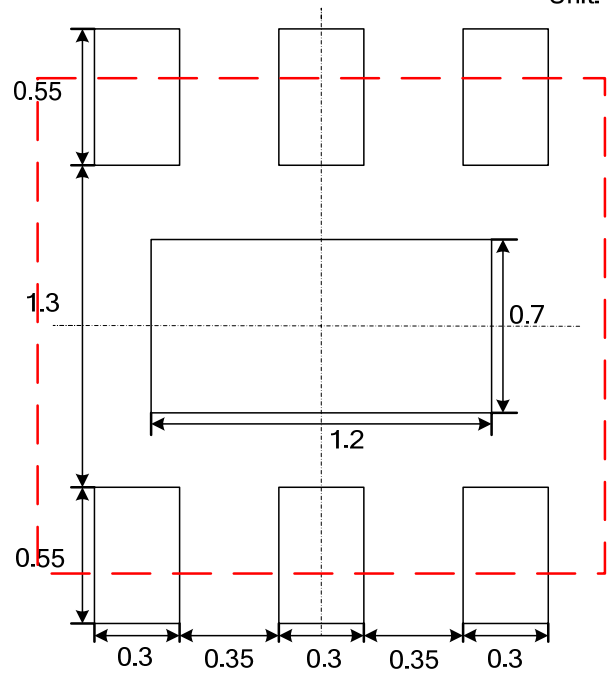
## PCB Layout

**SOT-23-6**



**DFNWB2\*2-6L**

Unit: mm





## RESTRICTIONS ON PRODUCT USE

- The information contained herein is subject to change without notice.
- BYD Microelectronics Co., Ltd. (short for BME) exerts the greatest possible effort to ensure high quality and reliability. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing BME products, to comply with the standards of safety in making a safe design for the entire system, including redundancy, fire-prevention measures, and malfunction prevention, to prevent any accidents, fires, or community damage that may ensue. In developing your designs, please ensure that BME products are used within specified operating ranges as set forth in the most recent BME products specifications.
- The BME products listed in this document are intended for usage in general electronics applications (computer, personal equipment, office equipment, measuring equipment, industrial robotics, domestic appliances, etc.). These BME products are neither intended nor warranted for usage in equipment that requires extraordinarily high quality and/or reliability or a malfunction or failure of which may cause loss of human life or bodily injury ("Unintended Usage"). Unintended Usage include atomic energy control instruments, airplane or spaceship instruments, transportation instruments, traffic signal instruments, combustion control instruments, medical instruments, all types of safety devices, etc.. Unintended Usage of BME products listed in this document shall be made at the customer's own risk.
- BME is not responsible for any problems caused by circuits or diagrams described herein whose related industrial properties, patents, or other rights belong to third parties. The application circuit examples explain typical applications of the products, and do not guarantee the success of any specific mass-production design.